







# Development of internal Sn Nb<sub>3</sub>Sn wires with internal oxidation

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#### **Outline of the presentation**

- State of the art on the internal oxidation process
- Nb<sub>3</sub>Sn wires are not created equal
  - Differences between PIT and RRP wires
  - Is there a better wire technology for accelerator magnets?
- Wires manufacturing at UNIGE
  - Monofilamentary wires
  - Simplified subelements
  - Multifilamentary wires with and without internal oxidation
- Conclusions

### The importance of oxidation for Nb<sub>3</sub>Sn





### State of the art of internally oxidized wires





### Manufacturing process: RRP vs PIT





Section of a Nb<sub>3</sub>Sn dipole magnet



Cabling degradation is much less pronounced in Internal Sn RRP wires compared to PIT wires



Distorted filaments produce Sn leak and thus are only partly reacted, leading to the lower I<sub>c</sub>

- S. Hopkins et al., IEEE Trans. Appl. Supercond., <u>34</u> (2024) 6001308 **DOI:** <u>10.1109/TASC.2024.3375274</u>
- M. Brown et al., Supercond. Sci. Technol., <u>29</u> (2016) 084008 **DOI:** <u>10.1088/0953-2048/29/8/084008</u>

Cumulative frequency

C. Segal et al., Supercond. Sci. Technol., <u>29</u> (2016)
 085003 DOI: <u>10.1088/0953-2048/29/8/085003</u>



# How it's made: high-J<sub>c</sub> internal Sn Nb<sub>3</sub>Sn wire



Critical current density  $\propto I/(grain size)$ 



# How it's made: high-J<sub>c</sub> internal Sn Nb<sub>3</sub>Sn wire





# The goals of our project at



- Develop a process to introduce oxide powder in an internal Sn rod-type wire to refine Nb<sub>3</sub>Sn grains
- Produce long prototype Nb<sub>3</sub>Sn wires (unit lengths <u>> 20 m</u>), matching the FCC targets for critical current density
  - Optimize the process for scaling up to an industrial production

#### The three steps to get there:

I. Monofilamentary wires: Material study Test of various alloys and oxides (and their combinations)



- 2. Simplified subelements: Current transport Deformation process, filaments arrangement and oxygen source configurations
- 3. Development of multifilamentary internal Sn rod-type wires with internal oxidation!







# Monofilamentary wires



Wire configuration



Nb-1wt%Zr + SnO<sub>2</sub>

Nb-7.5wt%Ta-1wt%Zr + SnO<sub>2</sub>

Nb-7.5wt%Ta-2wt%Zr + SnO<sub>2</sub>



 CrossMark
 Very high upper critical fields and enhanced critical current densities in Nb<sub>3</sub>Sn superconductors based on Nb–Ta–Zr alloys

 RECEIVED 20 December 2020
 and internal oxidation

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# Simplified multifilamentary wires layout and

configuration on the superconducting

### fabrication process



copper jacket



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9

### Effects of the internal oxidation on the superconducting properties



The FCC target for layer  $J_c$  is calculated based on the area fraction of reacted Nb<sub>3</sub>Sn in **RRP** wire for Hllumi



5000











Nb alloy	4.2 K, 99 % R no-OS	4.2 K, 99 % R Core-OS	4.2 K, 99 % R Annular-OS
Nb 7.5% <sup>wt</sup> Ta I% <sup>wt</sup> Zr	28.0 ± 0.6	28.97 ± 0.4	29.2 ± 0.4
Nb 7.5% <sup>wt</sup> Ta I% <sup>wt</sup> Hf	28.9 ± 0.6	29.0 ± 0.4	29.3 ± 0.4
Nb 7.5% <sup>wt</sup> Ta	28.0 ± 0.8	N/A	



#### Precipitates and pinning contribution

1.0

0.8

0.6

0.4

0.2 -

0.0 -

0.0

F<sub>p</sub> / F<sub>p</sub>(max)



<u>Change of dominant pinning mechanism</u> induced by the presence of <u>oxide precipitates</u>, Artificial Pinning Centers (APC), Shift with NbTaHf-alloy is larger



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12

 $F_p = J_c \times B$ 

### **XANES** investigation on precipitates

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#### X-Ray Absorption Spectroscopy to Investigate Precipitated Oxides in Nb<sub>3</sub>Sn Wires With an Internal Oxygen Source

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#### DOI: 10.1109/TASC.2024.3354232



Atomic specific technique, sensitive to the <u>chemistry</u> and to <u>crystal environment</u>



Phoenix Beamline Investigation of <u>Zr</u> <u>spectrum</u> in <u>different</u> <u>region</u> of the <u>reacted</u> (and unreacted) wires







PS

### What did we learn from XANES?



ZrO<sub>2</sub> precipitates due to the lower solubility of Zr and O in Nb<sub>3</sub>Sn compared to Nb

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ZrO<sub>2</sub>-like spectrum found only in Nb<sub>3</sub>Sn! Different Zr spectrum in residual alloy, despite oxygen diffusion



14



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#### Heat treatment optimization: reaction layer thickness

Heat treatment (HT): 550°C × 100 h + 650°C × 200 h

No OS

With OS





Introduction of OS reduces the Nb<sub>3</sub>Sn reaction kinetics

Higher temperature can promote reaction, but we want small grain size!

Significant increase of layer thickness at 700 °C

With OS 700 °C × 50 h



700 °C × 100 h













Heat treatment optimization: Influence of the Heat Treatment on the Layer  $J_{\rm C}$  of Internal-Sn Nb<sub>3</sub>Sn Wires With Internally **Oxidized Nanoparticles** F. Lonardo<sup>®</sup>, G. Bovone<sup>®</sup>, F. Buta, M. Bonura<sup>®</sup>, T. Bagni<sup>®</sup>, B. Medina-Clavijo<sup>®</sup>, A. Ballarino<sup>®</sup>, S. C. Hopkins<sup>®</sup>, T. Boutboul<sup>®</sup>, and C. Senatore<sup>®</sup>, *Senior Member, IEEE* 

radius of nanoparticles (nm)





#### Getting back the knowledge from industry

Fabrication of RRP wires was mainly carried by industry. Few academic study on the production, we need to gather the knowledge and close the gap



54/61



7/7 with

barrier

30/37

wires without OS, with

subelement containing

~ 200 filaments

Restacked wires manufactured with different layout, obtained in a max length of approx. 3 m



18

#### Approaches to implement internal oxidation

Where should we place the OS in a RRP wire?



**OS** at subelement level



Nb alloy filaments substituted with OS

OS inside each filament of the subelement

OS at filament level



#### **Does these approaches work?**

#### Heat treatment (HT): 550°C × 100 h + 650°C × 200 h



Wire fabricated with 7 subelements, made of 42 cold deformed NbTaHf alloy filaments.

Exploring how to implement the technique in extruded filaments and subelements.







Nb<sub>3</sub>Sn grains refined down to <u>**60 nm**</u>!!

Internal oxidation successfully implemented in a (short) Nb<sub>3</sub>Sn rod-type multifilamentary wire



20





# Summary and future perspectives

- Internal oxidation process proved by multiple sources to be an effective way to reach the FCC target for non-Cu J<sub>c</sub>
- Material studies on internally oxidised monofilamentary wires showed grain refinement and enhanced J<sub>c</sub> and B<sub>c2</sub>
- Presence of APCs in prototype rod-type subelement enhance layer J<sub>c</sub> above the FCC specifications in addition to record-<u>high B<sub>c2</sub></u> and change of pinning mechanism (point defect)
- X-Rays Absorption Near Edge Structure (XANES) on Nb<sub>3</sub>Sn wires shows the formation of the APC precipitates is concomitant to the formation of the Nb<sub>3</sub>Sn layer
- **Preliminary steps** moved in the fabrication of **extruded subelements and restacked wires** 
  - **Restacked wires** fabricated from **extruded subelement** with **NbTa alloy, without OS**
  - Grain refinement (60 nm) in a wire from cold-deformed subelements with NbTaHf and OS



Thank you for

your attention

#### ...and make Nb<sub>3</sub>Sn great again!